TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

T6C24

ROW DRIVER LSI FOR A DOT MATRIX LCD

The T6C24 is a row (common) driver LSI for a dot matrix LCD. The T6C24 generates the timing signals for the display using a built-in oscillator and also controls the T6C23 column (segment) LCD driver.

The T6C24 features a low-impedance 240-output row driver. The T6C24 also includes internal resistors to divide the bias voltage, a power supply op-amp and a contrast control circuit. The T6C24 can be used in conjunction with the T6C23 to construct a low-power LCD system.

Features

• Dot matrix graphic LCD row driver

• Built-in oscillator (additional external resistor)

Duty : 1/240

• Display OFF function : /DSPOF = L, all LCD outputs =

Low power consumption

• Logic power supply : 2.7 to 5.5 V • LCD power supply : 8.0 V to 30.0 V

CMOS process

 Package : TCP (Tape Carrier Package)

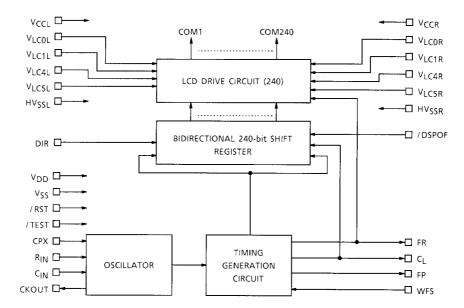
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T6C24	LEAD PITCH				
10024	IN	OUT			
(UAW)	1.2	0.22			
(UBW)	1.2	0.21			
(UFW, 6FS)	1.2	0.21			

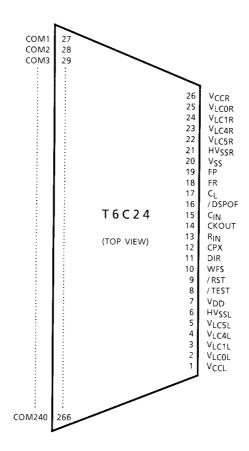
Please contact Toshiba or on authorized Toshiba dealer for information on package dimensions.

TCP (Tape Carrier Package)

Block Diagram



Pin Assignment



Note: The above diagram shows the pin configuration of the LSI chip; it does not show the configuration of the tape carrier package.

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Pin Functions

Pin Name	Pin No.	1/0	Functions		
COM1 to COM240	27 to 266	Output	Row driver outputs		
C _L	17	Output	Shift clock pulse		
FP	19	Output	Display synchronous signal		
FR	18	Output	Frame signal		
DIR	11	Input	Data flow direction select. Usually connected to V _{DD} DIR DATA FLOW		
			H COM1 → COM240		
			L COM240 → COM1		
WFS	10	Input	Frame signal inversion select. Usually connected to V _{DD} . WFS = H: FR phase change per 13 lines. WFS = L: FR phase change per 17 lines.		
/ DSPOF	16	Input	Display off. Usually connected to V _{DD} DSPOF = H: Display-on mode, (COM1 to COM240) are operational. DSPOF = L: Display-off mode, (COM1 to COM240) are at the V _{SS} level.		
/ RST	9	Input	/ RST = L: Reset state. Usually connected to V _{DD}		
СРХ	12	Input	Crystal oscillation / CR oscillation Select CPX = L : CR oscillation CPX = H: Crystal oscillation or external clock input from C _{IN}		
R _{IN}	13	Input	Connected to resistor for built-in oscillator		
C _{IN}	15	Input	Connected to crystal		
CKOUT	14	Output	Connected to resistor or crystal for built-in oscillator		
/ TEST	8	Input	Test pin. Usually connected to V _{DD}		
V _{DD} , V _{SS}	7, 20		Power supply		
VCCL, VCCR VLC0L, VLC0R VLC1L, VLC1R VLC4L, VLC4R VLC5L, VLC5R HVSSL, HVSSR	1, 26 2, 25 3, 24 4, 23 5, 22 6, 21	_	Power supply for LCD drive		

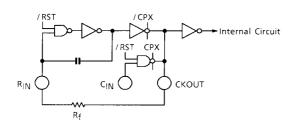
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Function of Each Block

Oscillator

The T6C24 has an on-chip oscillator (an external resistor is required).

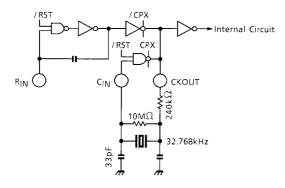
(1) CPX = L



R _f	f _{osc}			
390 kΩ	54 kHz			
620 kΩ	34 kHz			
780 kΩ	27 kHz			

Note: The resistor values are typical values. The oscillation frequency depends on how the device has been mounted. Hence R_f must be adjusted to achieve the target oscillation frequency.

(2) CPX = H



• Timing generation circuit

This circuit divides the oscillator frequency and generates the display timing signals (CL, FP and FR).

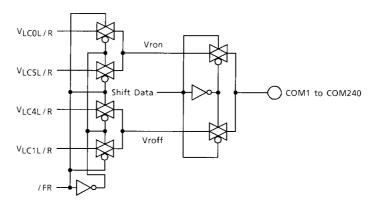
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• Shift register

240-bit shift register

• Row driver circuit and LCD voltage generation circuit

The T6C24 has 240 row drivers and four different LCD drive output voltage levels. The display data from the latch circuit and the M signal determine which of the four LCD drive voltage is selected. The voltage generation circuit and row driver circuit are shown in the following diagram.



Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Rating	Unit
Supply Voltage (1)	V _{DD} (Note 2)	-0.3 to 7.0	٧
Supply Voltage (2)	(Note 1, 2)	-0.3 to 32.0	V
Input Voltage	V _{in} (Note 2, 3)	-0.3 to V _{DD} + 0.3	٧
Operating Temperature	T _{opr}	−20 to 75	°C
Storage Temperature	T _{stg}	−55 to 125	°C

Note 1: V_{CCL} , V_{CCR} , V_{LC0L} , V_{LC0R} , V_{LC1L} , V_{LC1R} , V_{LC4L} , V_{LC4R} , V_{LC5L} and V_{LC5R}

Note 2: Referenced to VSS, HVSSL and HVSSR

Note 3: Applies to all data bus and I / O pins.

Note 4: Ensure that the following condition is always maintained.

 $V_{CCL/R} \ge V_{LC0L/R} \ge V_{LC1L/R} \ge V_{LC4L/R} \ge V_{LC5L/R} \ge HV_{SSL/R}$

Electrical Characteristics DC Characteristics Test Conditions (1)

Unless Otherwise Noted, V_{SS} = 0 V, V_{DD} = 3.0 V ± 10%, $V_{CCL/R}$ = 23.0 V ± 10%, $Ta = -20 \text{ to } 75^{\circ}C$

lt	em	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit	Pin Name
Operating Supply (1)		V_{DD}	_	_	2.7	_	3.3	V	V_{DD}
Operating	Supply (2)	V _{CC}	_	_	8.0	_	30.0	V	V _{CCL} , V _{CCR}
Input	H Level	V _{IH}	_	ı	0.7 V _{DD}	_	V _{DD}	V	WFS, CPX, DIR, / DSPOF, / RST, / TEST
Voltage	L Level	V_{IL}	_	ı	0	1	0.3 V _{DD}	>	
Output	H Level	V _{OH}	_	I _{OH} = -400 μA	V _{DD} - 0.4		ı	>	· C _L , FP, FR
Voltage	L Level	V_{OL}	_	I _{OL} = 400 μA	V_{SS}	1	V _{SS} +0.4	>	
Row Drive Resistanc		Rrow	_	(Note 5) Load voltage = output level of 0.5 V	_	_	1.5	kΩ	COM1 to COM240
Input Leak	kage	I _{IL}	_	V _{IN} = V _{DD} to GND	-1	_	1	μA	WFS, CPX, DIR, / DSPOF, / RST, / TEST
Current Co	onsumption	I _{SS}	_	(Note 1)	_	-35	-50	μΑ	V _{DD}
Current Co (2)	onsumption	I _{CC}	_	(Note 2)	_	10	20	μΑ	V _{CCL} , V _{CCR} V _{LC0L} , V _{LC0R}
Current Co	onsumption	I _{DOF}	_	(Note 3)	_	25	40	μΑ	V _{SS} , V _{SSL} , V _{SSR} V _{LC5L} , V _{LC5R}
Current Co (4)	onsumption	I _{STB}	_	(Note 4)	-1	1	1	μΑ	$\begin{matrix} V_{SS}, V_{SSL}, V_{SSR} \\ V_{LC5L}, V_{LC5R} \end{matrix}$
Operating Freq.		f _{osc}	_	_	20	_	100	kHz	R _{IN} , C _{IN}
External C Frequency		f _{ex}	_	_	20	_	100	kHz	C _{IN}
External Clock Duty		f _{duty}		_	40	50	60	%	C _{IN}
External C Fall Time	Clock Rise /	t _r / t _f	_	-	_	_	50	ns	C _{IN}

Note 1: Logic current : V_{DD} = 3.0 V ± 10%, Ta = 25°C, R_f = 620 k Ω (33.6 kHz), no load Note 2: LCD driver current : V_{DD} = 3.0 V ± 10%, $V_{CCL/R}$ = 23.0 V, Ta = 25°C, 1 / 13 bias,

 $R_f = 620 \text{ k}\Omega$, no load

Note 3: Display-off current : V_{DD} = 3.0 V ± 10%, $V_{CCL/R}$ = 23.0 V, Ta = 25°C, 1 / 13 bias,

 R_f = 620 k Ω , / DSPOF = L, no load

Note 4: Standby current : V_{DD} = 3.0 V ± 10%, $V_{CCL/R}$ = 23.0 V, Ta = 25°C, 1 / 13 bias,

 R_f = 620 k Ω , / RST = L, no load

Note 5: $V_{CCL/R} = V_{LC0L/R} = 23.0 \text{ V}$, $V_{LC1L/R} = V_{CC} \times 12/13$, $V_{LC4L/R} = V_{CC} \times 1/13$,

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 $HV_{SSL/R} = V_{LC5L/R} = 0 V$

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Test Conditions (2)

(Unless Otherwise Noted, V_{SS} = 0 V, V_{DD} = 5.0 V ± 10%, $V_{CCL/R}$ = 23.0 V ± 10%, $V_{CCL/R}$

lte	em	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit	Pin Name
Operating Supply (1)		V_{DD}	_	_	4.5	_	5.5	V	V_{DD}
Operating	Supply (2)	V _{CC}	_	_	8.0	_	30.0	V	V _{CCL} , V _{CCR}
Input	H Level	V_{IH}	_	_	0.7 V _{DD}	_	V _{DD}	V	WFS, CPX, DIR, / DSPOF, / RST, / TEST
Voltage	L Level	V_{IH}	_	_	0	_	0.3 V _{DD}	V	
Output	H Level	V_{OH}	_	I _{OH} = -400 μA	V _{DD} - 0.4	1	1	V	· C _L , FP, FR
Voltage	L Level	V_{OL}	_	I _{OL} = 400 μA	V_{SS}	_	V _{SS} + 0.4	V	
Row Driver Output Resistance		Rrow	_	(Note 5) Load voltage = output level of 0.5 V	_	_	1.5	kΩ	COM1 to COM240
Input Leak	age	I _{IL}	_	V _{IN} = V _{DD} to GND	-1	_	1	μA	WFS, CPX, DIR, / DSPOF, / RST, / TEST
Current Co (1)	nsumption	I _{SS}	_	(Note 1)	_	-60	-90	μΑ	V _{DD}
Current Co (2)	nsumption	I _{CC}	_	(Note 2)	_	10	20	μA	V _{CCL} , V _{CCR} V _{LC0L} , V _{LC0R}
Current Co (3)	nsumption	I _{DOF}	_	(Note 3)	_	50	80	μΑ	V _{SS} , V _{SSL} , V _{SSR} V _{LC5L} , V _{LC5R}
Current Co (4)	nsumption	I _{STB}	_	(Note 4)	-1	_	1	μA	V _{SS} , V _{SSL} , V _{SSR} V _{LC5L} , V _{LC5R}
Operating Freq.		f _{osc}	_	_	20	_	100	kHz	R _{IN} , C _{IN}
External C Frequency		f _{ex}	_	_	20	_	100	kHz	C _{IN}
External Clock Duty		f _{duty}	_	_	40	50	60	%	C _{IN}
External C Fall Time	ock Rise /	t _r / t _f	_	-	_	_	50	ns	C _{IN}

Note 1: Logic current : V_{DD} = 5.0 V ± 10%, Ta = 25°C, R_f = 620 k Ω (33.6 kHz), no load Note 2: LCD driver current : V_{DD} = 5.0 V ± 10%, $V_{CCL/R}$ = 23.0 V, Ta = 25°C, 1 / 13 bias,

 $R_f = 620 \text{ k}\Omega$, no load

Note 3: Display-off current : V_{DD} = 5.0 V ± 10%, $V_{CCL/R}$ = 23.0 V, Ta = 25°C, 1 / 13 bias,

 $R_f = 620 \text{ k}\Omega$, / DSPOF = L, no load

Note 4: Standby current : V_{DD} = 5.0 V ± 10%, $V_{CCL/R}$ = 23.0 V, Ta = 25°C, 1 / 13 bias,

 R_f = 620 k Ω , / RST = L, no load

Note 5: $V_{CCL/R} = V_{LC0L/R} = 23.0 \text{ V}, V_{LC1L/R} = V_{CC} \times 12 / 13, V_{LC4L/R} = V_{CC} \times 1 / 13, H_{VSSL/R} = V_{LC5L/R} = 0 \text{ V}$

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